



# MProbe<sup>®</sup> 20 Thin Film Measurement Systems

*It is easy to be an expert with MProbe*

Majority of translucent or lightly absorbing films can be measured quickly and reliably: Oxides, Nitrides, Photoresists, Polymers, Semiconductors (Si, aSi, polySi), Compound Semiconductors (AlGaAs, InGaAs, CdTe, CIGS), Hard coatings (SiC, DLC), Polymer films and coatings (Paralene, PMMA, Polyamides), thin metal films and many more.

**Thickness Range: 1 nm - 1.8 mm**

**Wavelength Range: 200nm -1700nm**

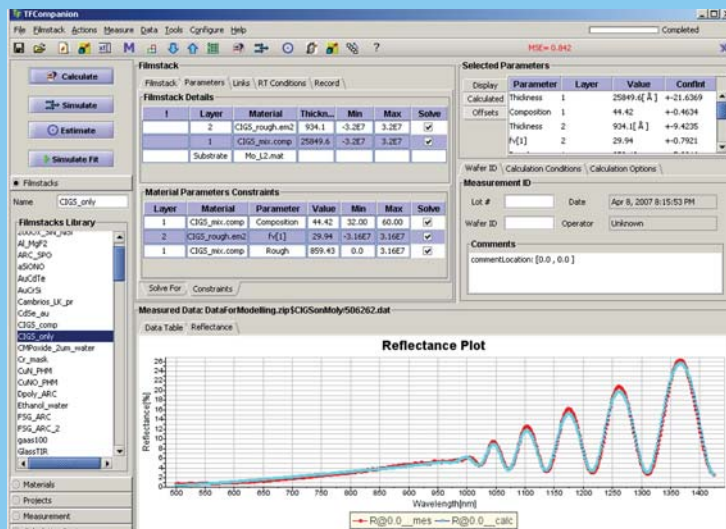
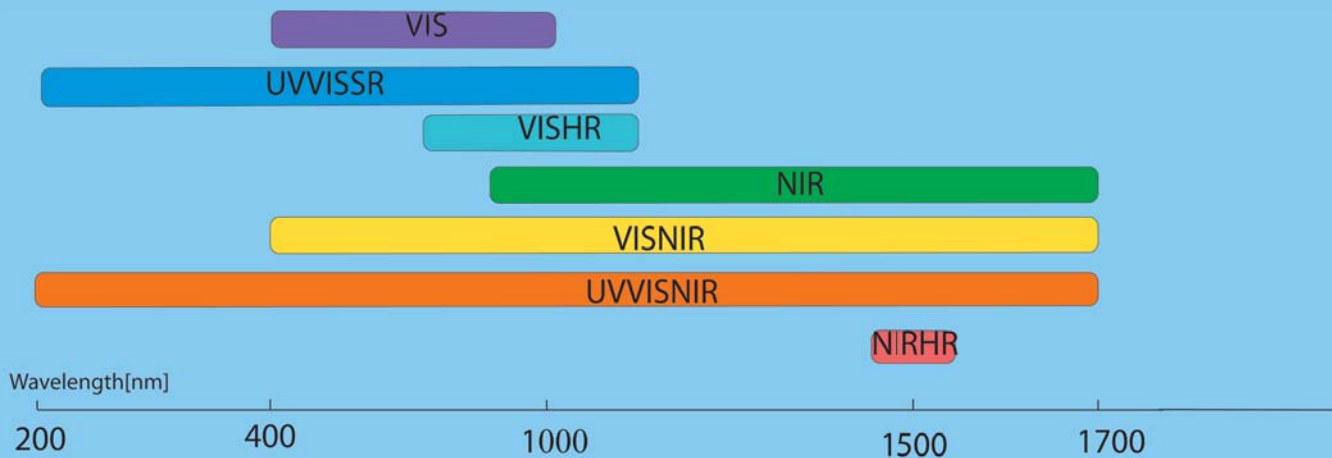
**Spot size: 0.5 mm**

Thin Solar Cells applications: aSi, TCO, CIGS, CdS, CdTe - full solar stack measurement. LCD, FPD application: ITO, Cell Gaps, Polyamides. Optical Coatings: dielectric filters, hardness coating, anti-reflection coating Semiconductor and dielectrics: Oxides, Nitrides, OLED stack

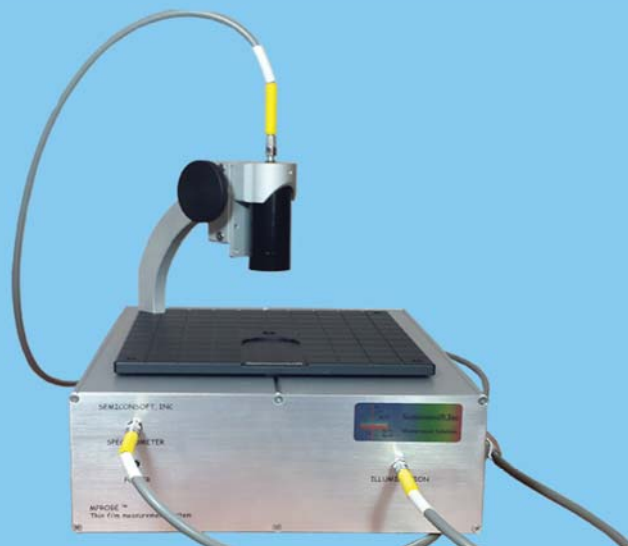
## MProbe Advantage:

- Extensive materials library (500+), parametrized materials support
- Real-time, one-click measurement and analysis
- thickness, n&k and roughness measurement
- user friendly desktop software, no expert knowledge required -everybody is an expert
- powerful software tools: simulation, background/ scaling correction, multisample measurement, dynamic measurement
- Measurement history: recall/display measurement results and statistics
- free support and software update for 12 months

Precision	<0.01nm or 0.01%
Accuracy	<0.2% or 1 nm
Stability	<0.02nm or 0.03%
Spot Size	2 mm standard, 0.5 mm with lens
Sample Size	from 5 mm

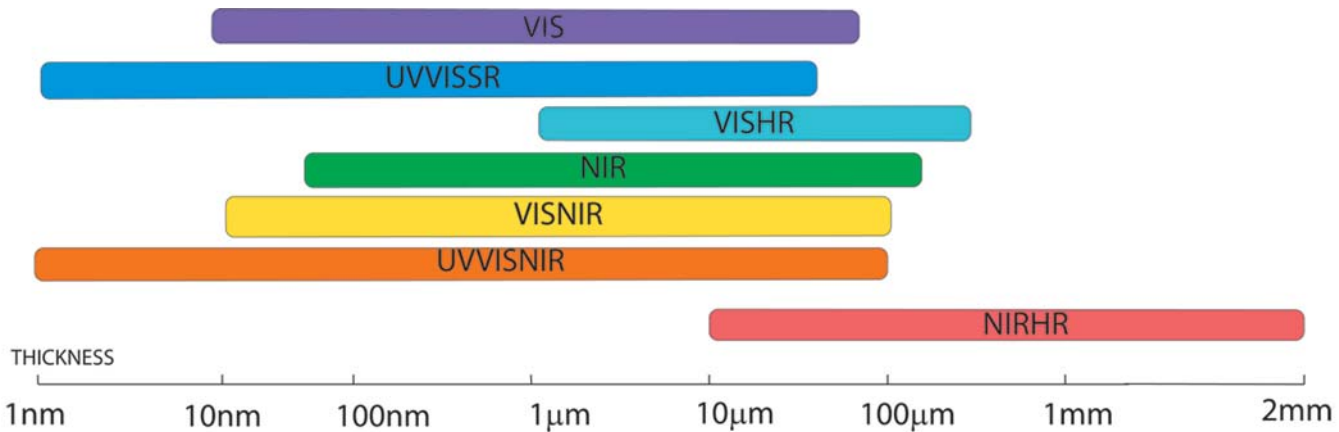


Cds/CIGS stack results  
it measured vs. generated data



MProbe system (desktop configuration)

# Standard Configurations/Basic Specification



**MPROBE 20 line** includes different configuration of desktop system. Main standard configurations are described below. See individual system brochure for detailed info

Model	Wavelength range	Spectrometer/Detector/Light source	Thickness range*
<b>VIS</b>	400-1100 nm	Spectrometer F4/Si 3600 pixels/ Tungsten - Halogen light source	10 nm to 75 µm
<b>UVVisSR</b>	200-1000 nm	Spectrometer F4/ Si CCD 2048 pixels/ Deuterium & Tungsten-Halogen light source	1 nm to 75 µm (option:up to 150 µm)
<b>VISHR</b>	700-1100 nm	HR Spectrometer F4/Si 2048 pixels/ Tungsten - Halogen light source	1 µm to 400 µm
<b>NIR</b>	900-1700nm	NIR F4/512 InGaAs PDA/Tungsten-Halogen light source	50 nm-100 µm
<b>VISNIR</b>	400-1700 nm	Spectrometer F4 Si CCD 3600 pixels(Vis channel);NIR F4/512 InGaAs PDA( NIR channel) Tungsten-Halogen light source	10 nm to 100 µm
<b>UVVIS-NIR</b>	200 -1700 nm	Spectrometer F4 Si CCD 2048 pixels(UVVis channel);NIR F4/512 In-GaAs PDA( NIR channel) Deuterium & Tungsten-Halogen light source	1 nm -100 µm
<b>VisLX</b>	400-1100 nm	F4/Si 2048 pixels, Tungsten Halogen light source. High frequency measurement version of MProbe Vis system (LAN interface, 10µs integration time )	10 nm- 70 µm
<b>NIRHR</b>	1500-1550 nm	NIR F4/512 InGaAs PDA/Tungsten-Halogen light source or SLD (super-luminescent diode)	10 µm-1800 µm(quartz) 4 µm -500 µm( Si )

\* T, n & k measurement in 25nm - 20µm thickness range.

Maximum thickness limits are listed for R.I.= 1.5

Other configuration are available. OEM inquiries and custom development projects are welcome.

One year limited warranty on labor and materials for all system

Semiconsoft, Inc, 2018

tel. +1.617.388.6832 email: info@semiconsoft.com fax.+1.508.858.5473

Visit us : <http://www.semiconsoft.com>